

2304

4.0 Watts - 20 Volts, Class C Microwave 2300 MHz

GENERAL DESCRIPTION

The 2304 is a COMMON BASE transistor capable of providing 4 Watts Class C, RF output power at 2300 MHz. Gold metalization and diffused ballasting are used to provide high reliability and supreme ruggedness. The transistor uses a fully hermetic High Temperature Solder Sealed package.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C 10.2 Watts

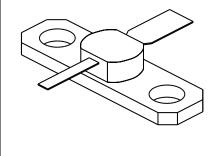
Maximum Voltage and Current

BVces Collector to Emitter Voltage 45 Volts
BVebo Emitter to Base Voltage 3.5 Volts
Ic Collector Current 0.6 A

Maximum Temperatures

 $\begin{array}{ll} \mbox{Storage Temperature} & -65 \mbox{ to} + 200 \mbox{°C} \\ \mbox{Operating Junction Temperature} & + 200 \mbox{°C} \end{array}$

CASE OUTLINE 55 BT- Style 1



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg η _c VSWR ₁	Power Out Power Input Power Gain Collector Efficiency Load Mismatch Tolerance	F = 2.3 GHz Vcb = 20 Volts Po = 4 Watts As Above F = 2.3 GHz, Po = 4 W	4.0 8.0	40	0.63	Watt Watt dB %

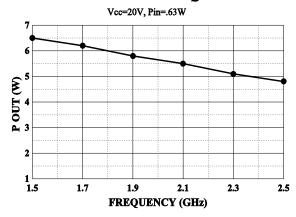
$\begin{array}{ccc} \textbf{BVebo} & \textbf{Emit} \\ \textbf{Icbo} & \textbf{Collo} \\ \textbf{h}_{FE} & \textbf{Curr} \\ \textbf{Cob} & \textbf{Outp} \end{array}$	ector to Emitter Breakdown tter to Base Breakdown ector to Base Current rent Gain out Capacitance	Ic = 30 mA Ie = 3.0 mA Vcb = 22 Volts Vce = 5 V, Ic = 300 mA F = 1.0 MHz, Vcb = 22 V	45 3.5 10	7.0	1.5	Volts Volts mA pF °C/W
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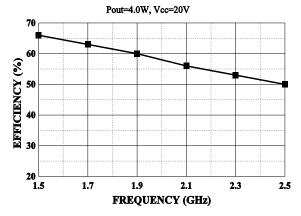
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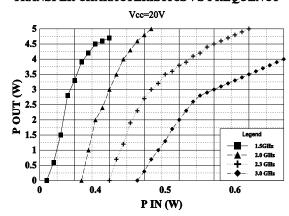
POWER OUTPUT VS FREQUENCY



EFFICIENCY VS FREQUENCY



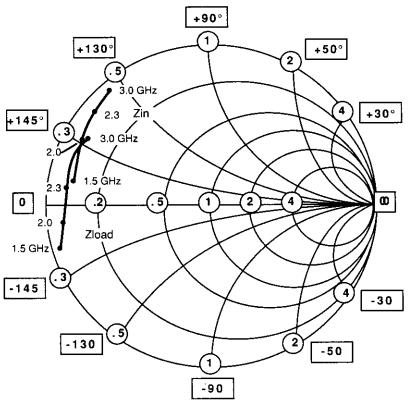
TRANSFER CHARACTERISTICS VS FREQUENCY



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SMITH CHART

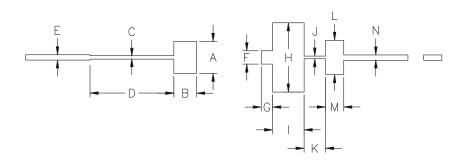
NORMALIZED IMPEDANCE AND ADMITTANCE COORDINATES



NORMALIZED TO A 50 OHM SYSTEM.

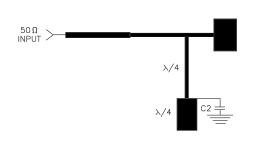
FREQUENCY MHz	R Zi	n JX	FREQUENCY MHz	Zloa R	ad JX
1500	4	5	1500	3.9	16
2000	3.3	15	2000	2.7	3
2300	3.0	18	2300	2.6	-3
3000	2.5	2 2	3000	1.8	-7.5

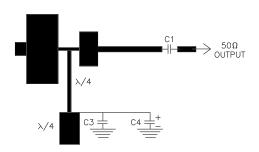
REVISIONS						
ZONE	REV	DESCRIPTION	DATE	APPROVED		



DIM	INCHES		
Α	.350		
В	.250		
С	.038		
D	.920		
Ε	.058		
F	.145		
G	.125		
Н	.760		
1	.345		
J	.030		
K	.235		
L	.375		
М	.200		
N	.058		

2304 TEST CIRCUIT F = 2.3 GHz





= Microstrip on 0.010" Duroid, Er=2.3 C1,C2 = 100PF ATC "A" C3 = 82PF ATC "B" C4 = 10MFD 35v



cage OPJR2	DWG NO.	2304		REV B
	SCALE	1/1	SHEET	

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